Stabistor diodes — high speed, multi-pellet general purpose

FEATURES

- Voltages from 1.210 to 3.700
- · Tightly controlled forward voltages
- Double plug DO-35 package
- Multi-pellet design

MAXIMUM RATINGS

- Junction Temperature -65°C to + 175°C
- Storage Temperature -65°C to + 175°C
- DC Power Dissipation: 400mW @ T, = 30°C
- Derate above 25°C: 2.67mW/°C

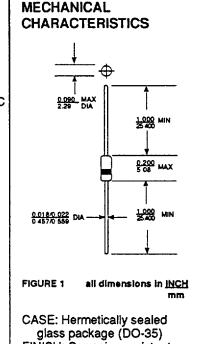
Stabistors are high conductance diffused silicon diodes with tightly controlled forward voltage characteristics. They are generally operated in the forward region and are designed to be used as stable forward reference sources.

They are manufactured with 2, 3 or 4 diode pellets in series and thus have a linear temperature response [mv/°c] over their ambient temperature range.

These devices are ideal in such applications as voltage regulation, sensing, comparing, protecting and in computer circuitry. Their highly controlled conductance is necessary for the design of clippers, dc coupling circuits, clamping circuits, meter protectors, bias regulators, low power clipping, level shifting, voltage regulation, temperature stabilization of transistor base-emitter biasing network and in many other applications where tight tolerances and low voltage levels are required.

ELECTRICAL CHARACTERISTICS @ 25°C

Туре	Forward Voltage V, Volta		Test Current	Maximum Reverse Leakage Current
	Minimum	Maximum	l _p mA	i _n @ 10V μΑ
APD200	1,220 1,390 1,600	1,340 1,540 1,760	1 10 100	10
APD300	1.840 2.100 2.400	2.030 2.330 2.650	1 10 100	10 .
APD400	2.470 2.800 3.160	2.710 3.070 3.490	1 10 100	10
AP4156	1.210 1.380 1.540	1.410 1.580 1.840	1 10 100	10
AP4157	1.850 2.120 2.360	2.050 2.320 2.660	1 10 100	10
AP5179	2.200 2.600 3.000	2.800 3.200 3.700	1 10 100	10



glass package (DO-35)
FINISH: Corrosion resistant.
Leads are tin plated.
POLARITY: Cathode banded.
WEIGHT: 0.2 grams (typ).

This series also offered in DO-7 package. Consult factory for availability.

